

EAST Search History


Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	2	"6246243".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/02 19:41
L2	6	semi adj fusible adj link	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/02 20:37
L3	0	semifusible adj link	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/02 19:45
L4	6	semi\$1fusible adj link	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/02 19:45
L5	20	semi adj fusible	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/02 19:47
L6	500	semi adj fus\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/02 19:56
L7	6	semi adj fus\$4 adj link	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/02 19:48
L8	1	(thin adj film adj transistor) same (blow adj fuse)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/02 20:01

EAST Search History

L9	23	(thin adj film adj transistor) and (blow adj fuse)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/02 20:03
L10	0	(thin adj film adj transistor) and (blow same semi\$1fuse)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/02 20:04
L11	0	(thin adj film adj transistor) and (blow same semi\$1fuse)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/02 20:05
L12	3	(blow same semi\$1fuse)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/02 20:06
L13	30	(semi\$1fuse)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/02 20:10
L14	85	(semi adj fuse)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/02 20:11
L15	9	(semi adj fus\$4) and (metal adj (layer or film))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/02 20:16
L16	3	(semi adj fus\$4) and (select\$3 adj (circuit or device))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/02 20:18

EAST Search History

L17	3	(semi adj fus\$4) and (thin adj film adj resistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/02 20:19
L18	3	(semi\$1fus\$4) and (thin adj film adj resistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/02 20:19
L19	0	(semifus\$4) and (thin adj film adj resistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/02 20:19
L20	4	(semi adj fus\$4) and (active adj circuit)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/02 20:19
L21	444	257/209.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/02 20:37

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IDS Flag Clearance for Application 10777337

**IDS
Information**

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